

ADG221/ADG222

FEATURES

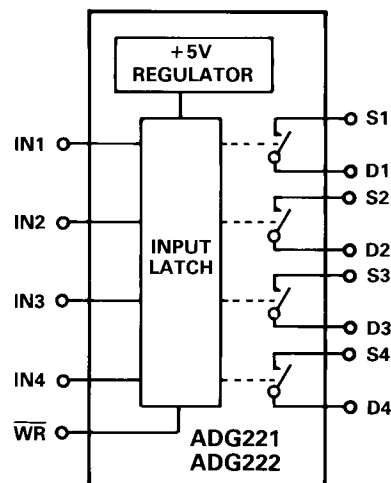
44V Supply Maximum Rating
±15V Analog Signal Range
Low R_{ON} (60Ω)
Low Leakage (0.5nA)
Break-Before-Make Switching
Extended Plastic Temperature Range
 (–40°C to +85°C)
Low Power Dissipation (25.5mW)
μP, TTL, CMOS Compatible
Available in 16-Lead DIP/SOIC and
20-Lead PLCC/LCCC Packages
Surface Mount Packages
Superior DG221 Replacement

GENERAL DESCRIPTION

The ADG221 and ADG222 are monolithic CMOS devices comprising four independently selectable switches. On-chip latches facilitate microprocessor interfacing. They are designed on an enhanced LC²MOS process which gives an increased signal handling capability of ±15V. These switches also feature high switching speeds and low R_{ON}.

The ADG221 and ADG222 consist of four SPST switches. They differ only in that the digital control logic is inverted. All devices exhibit break before make switching action. Inherent in the design is low charge injection for minimum transients when switching the digital inputs.

FUNCTIONAL BLOCK DIAGRAM



PRODUCT HIGHLIGHTS

- Easily Interfaced:**
 Digital inputs are latched with a $\overline{WR}$ signal for microprocessor interfacing. A 5V regulated supply is internally generated permitting wider tolerances on the supplies without affecting the TTL digital input switching levels.
- Single Supply Operation:**
 For applications where the analog signal is unipolar (0V to 15V), the switches can be operated from a single +15V supply.
- Low Leakage:**
 Leakage currents in the range of 500pA make these switches suitable for high precision circuits. The added feature of Break-before-Make switching allows for multiple outputs to be tied together for multiplexer applications while keeping leakage errors to a minimum.

$\overline{WR}$	ADG221 IN	ADG222 IN	SWITCH CONDITION
0	0	1	ON
0	1	0	OFF
1	X	X	Retains Previous Switch Condition

Table I. Truth Table

REV. B

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ADG221/ADG222—SPECIFICATIONS ($V_{DD} = +15V$, $V_{SS} = -15V$, unless otherwise specified)

Parameter	K Version		B Version		T Version		Units	Test Conditions
	25°C	−40°C to +85°C	25°C	−40°C to +85°C	25°C	−55°C to +125°C		
ANALOG SWITCH								
Analog Signal Range	± 15	± 15	± 15	± 15	± 15	± 15	Volts	− 10V≤V _S ≤ + 10V I _{DS} = 1.0mA Test Circuit 1
R _{ON}	60		60		60		Ω typ	
	90	145	90	145	90	145	Ω max	
R _{ON} vs. V _D (V _S)	20		20		20		% typ	V _S = 0V, I _{DS} = 1mA V _D = ± 14V; V _S = ± 14V; Test Circuit 2
R _{ON} Drift	0.5		0.5		0.5		%/°C typ	
R _{ON} Match	5		5		5		% typ	
I _S (OFF)	0.5		0.5		0.5		nA typ	V _D = ± 14V; V _S = ± 14V; Test Circuit 2
OFF Input Leakage	2	100	2	100	1	100	nA max	
I _D (OFF)	0.5		0.5		0.5		nA typ	V _D = ± 14V; V _S = ± 14V; Test Circuit 2
OFF Output Leakage	2	100	2	100	1	100	nA max	
I _D (ON)	0.5		0.5		0.5		nA typ	V _D = ± 14V; Test Circuit 3
ON Channel Leakage	2	200	2	200	1	200	nA max	
DIGITAL CONTROL								
V _{INH} , Input High Voltage		2.4		2.4		2.4	V min	
V _{INL} , Input Low Voltage		0.8		0.8		0.8	V max	
I _{INL} or I _{INH}		1		1		1	μA max	
DYNAMIC CHARACTERISTICS								
t _{OPEN}	30		30		30		ns typ	Test Circuit 4
t _{ON} ¹	300		300		300		ns max	
t _{OFF} ¹	250		250		250		ns max	
t _W ¹ Write Pulse Width		100		100	100	120	ns min	See Figure 2
t _S ¹ Digital Input Setup Time		100		100	100	120	ns min	See Figure 2
t _H ¹ Digital Input Hold Time		20		20	20	20	ns min	See Figure 2
OFF Isolation	80		80		80		dB typ	V _S = 10V (p-p); f = 100kHz R _L = 75Ω; Test Circuit 6 Test Circuit 7
Channel-to-Channel Crosstalk	80		80		80		dB typ	
C _S (OFF)	5		5		5		pF typ	
C _D (OFF)	5		5		5		pF typ	R _S = 0Ω; C _L = 1000pF; V _S = 0V Test Circuit 5
C _D , C _S (ON)	16		16		16		pF typ	
C _{IN} Digital Input Capacitance	5		5		5		pF typ	
Q _{INJ} Charge Injection	20		20		20		pC typ	
POWER SUPPLY								
I _{DD}	0.6		0.6		0.6		mA typ	Digital Inputs = V _{INL} or V _{INH}
I _{DD}		1.5		1.5		1.5	mA max	
I _{SS}	0.1		0.1		0.1		mA typ	
I _{SS}		0.2		0.2		0.2	mA max	
Power Dissipation		25.5		25.5		25.5	mW max	

NOTE

¹Sample tested at 25°C to ensure compliance.

t_{ON} , t_{OFF} are the same for both IN and WR digital input changes.

Specifications subject to change without notice.

ABSOLUTE MAXIMUM RATINGS*

($T_A = +25°C$ unless otherwise stated)

V_{DD} to V_{SS} 44V

V_{DD} to GND 25V

V_{SS} to GND –25V

Analog Inputs¹

Voltage at S, D $V_{SS} - 0.3V$ to $V_{DD} + 0.3V$

Continuous Current, S or D 30mA

Pulsed Current S or D

1ms Duration, 10% Duty Cycle 70mA

Digital Inputs¹

Voltage at IN, WR $V_{SS} - 2V$ to $V_{DD} + 2V$ or 20mA, Whichever Occurs First

Power Dissipation (Any Package)

Up to +75°C 470mW

Derates above +75°C by 6mW/°C

Operating Temperature

Commercial (K Version) –40°C to +85°C

Industrial (B Version) –40°C to +85°C

Extended (T Version) –55°C to +125°C

Storage Temperature –65°C to +150°C

Lead Temperature (Soldering 10sec) +300°C

NOTE

¹Overvoltage at IN, WR, S or D will be clamped by diodes. Current should be limited to the Maximum Rating above.

*COMMENT: Stresses above those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Only one Absolute Maximum Rating may be applied at any one time.

CAUTION

ESD (electrostatic discharge) sensitive device. The digital control inputs are diode protected; however, permanent damage may occur on unconnected devices subject to high energy electrostatic fields. Unused devices must be stored in conductive foam or shunts. The protective foam should be discharged to the destination socket before devices are removed.



ORDERING GUIDE

Model ¹	Temperature Range	Package Option ²
ADG221KN	-40°C to +85°C	N-16
ADG221KR	-40°C to +85°C	R-16A
ADG221KP	-40°C to +85°C	P-20A
ADG221BQ	-40°C to +85°C	Q-16
ADG221TQ	-55°C to +125°C	Q-16
ADG221TE	-55°C to +125°C	E-20A
ADG222KN	-40°C to +85°C	N-16
ADG222KR	-40°C to +85°C	R-16A
ADG222KP	-40°C to +85°C	P-20A
ADG222BQ	-40°C to +85°C	Q-16
ADG222TQ	-55°C to +125°C	Q-16
ADG222TE	-55°C to +125°C	E-20A

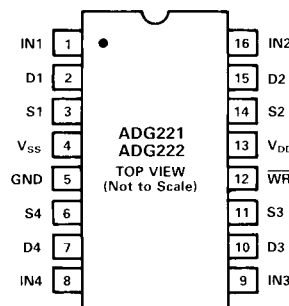
NOTES

¹To order MIL-STD-883, Class B processed parts, add /883B to T grade part numbers. See Analog Devices Military Products Databook (1990) for military data sheet.

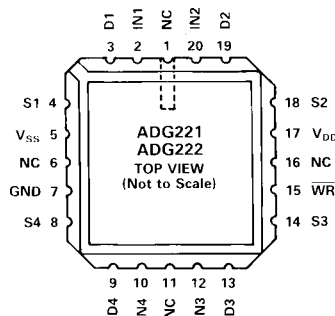
²N = Plastic DIP; R = 0.15" Small Outline IC (SOIC); P = Plastic Leaded Chip Carrier (PLCC); Q = Cerdip; E = Leadless Ceramic Chip Carrier (LCCC).

PIN CONFIGURATIONS

DIP, SOIC

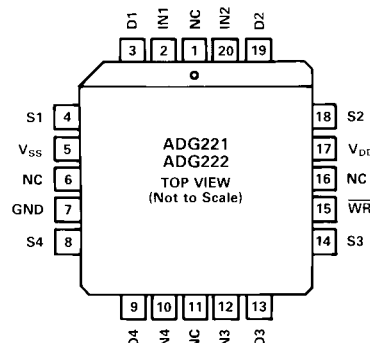


LCCC



NC = NO CONNECT

PLCC



NC = NO CONNECT

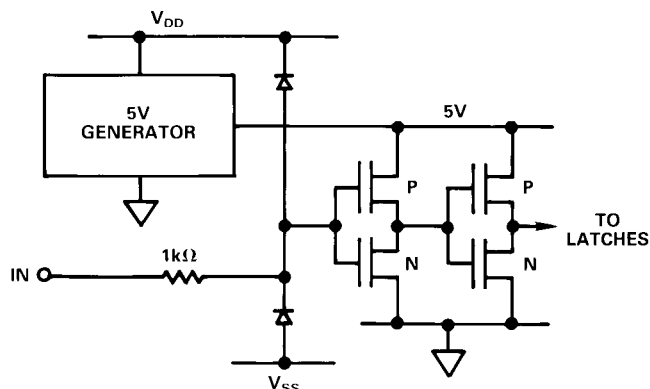


Figure 1. Typical Digital Input Cell

TIMING AND CONTROL SEQUENCE

Figure 2 shows the timing sequence for latching the switch digital inputs (IN1 – IN4). The latches are level sensitive and, therefore, while $\overline{WR}$ is held low the latches are transparent and the switches respond to the digital inputs. The digital inputs are latched on the rising edge of $\overline{WR}$.

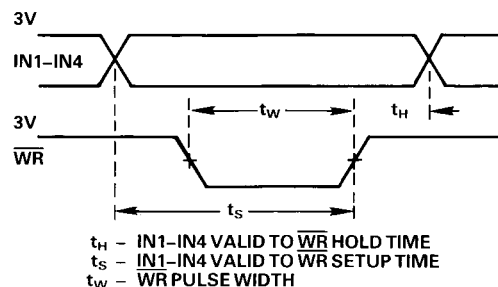
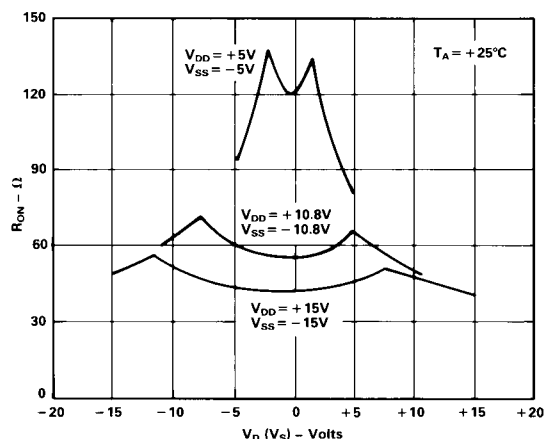


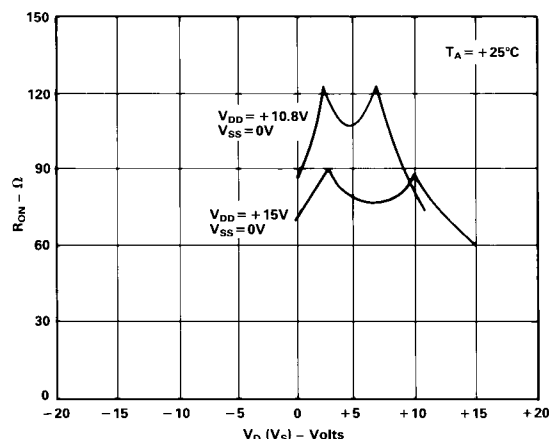
Figure 2. Timing and Control Sequence

ADG221/ADG222—Typical Performance Characteristics

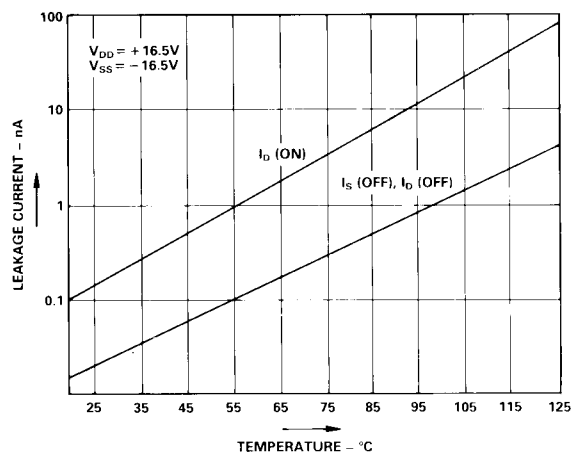
The switches are guaranteed functional with reduced single or dual supplies down to 4.5V.



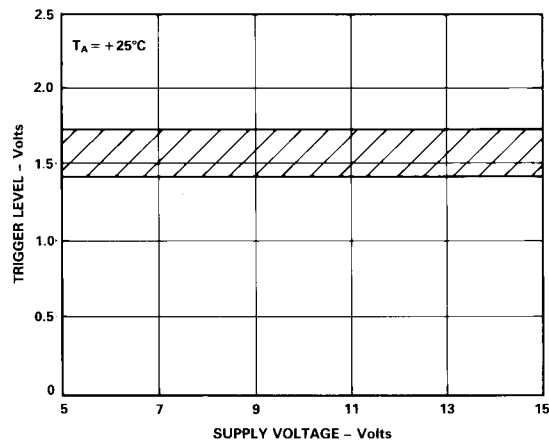
R_{ON} as a Function of V_D (V_S): Dual Supply Voltage



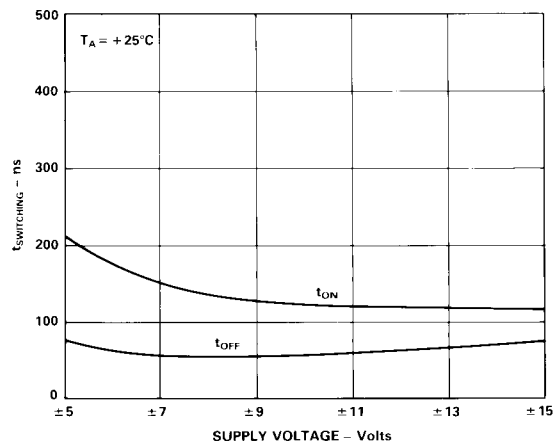
R_{ON} as a Function of V_D (V_S): Single Supply Voltage



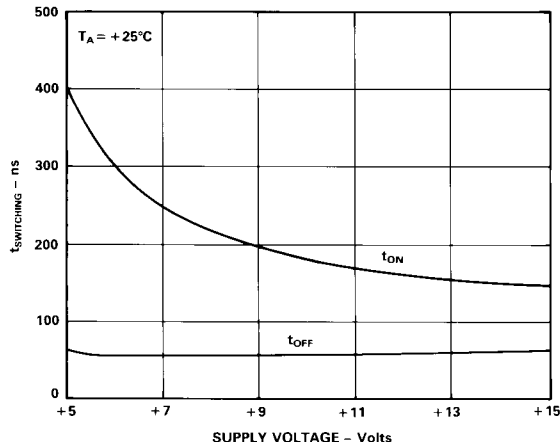
Leakage Current as a Function of Temperature (Note: Leakage Currents Reduce as the Supply Voltages Reduce)



Trigger Level vs. Power Supply Voltage: Dual or Single Supply Voltage

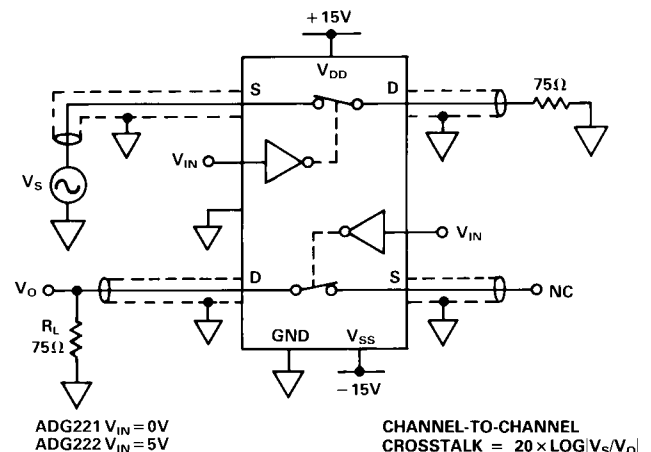
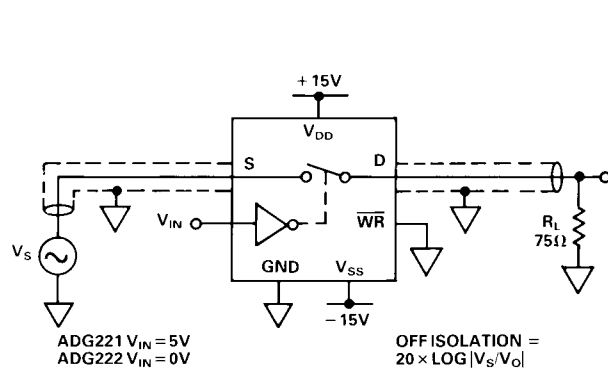
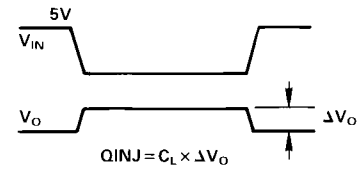
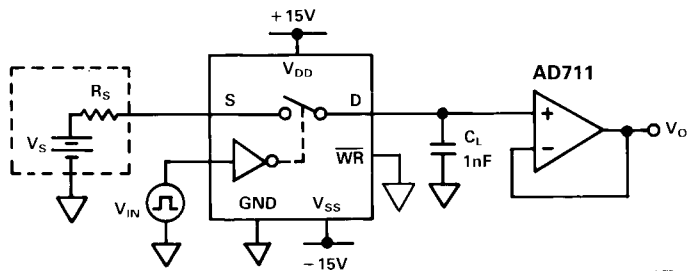
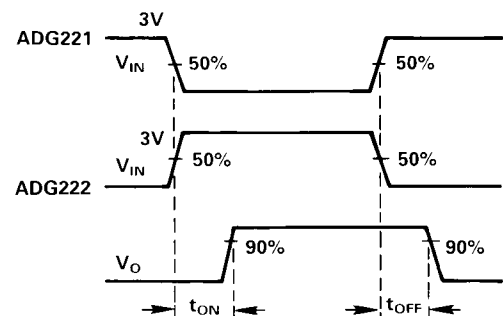
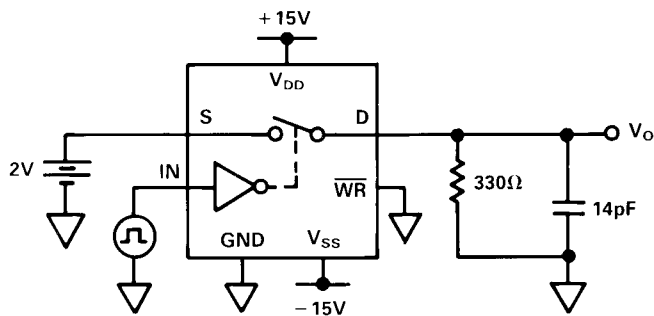
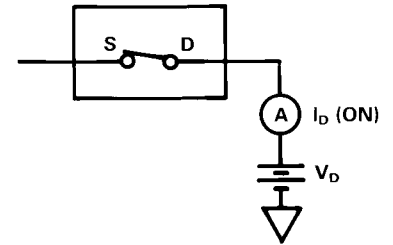
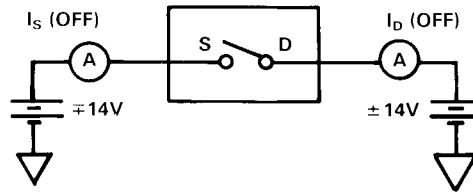
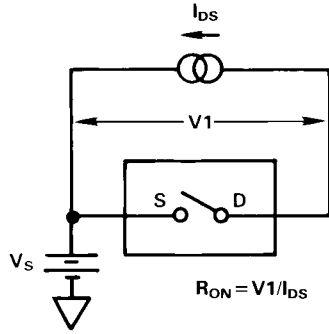


Switching Times vs. Supply Voltage (Dual Supply)



Switching Times vs. Supply Voltage (Single Supply)

Test Circuits—ADG221/ADG222



ADG221/ADG222

TERMINOLOGY

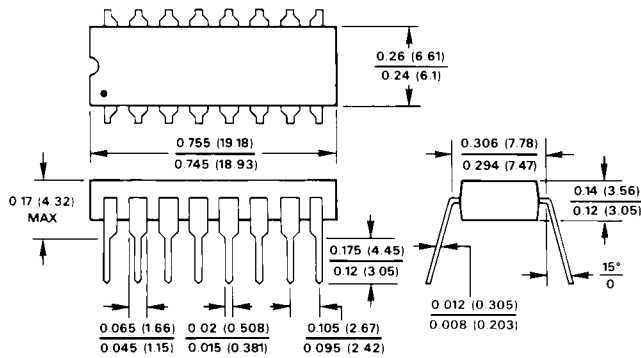
R_{ON}	Ohmic resistance between terminals OUT and S
R_{ON} Match	Difference between the R_{ON} of any two channels
I_S (OFF)	Source terminal leakage current when the switch is off
I_D (OFF)	Drain terminal leakage current when the switch is off
I_D (ON)	Leakage current that flows from the closed switch into the body
V_D (V_S)	Analog voltage on terminal D, S
C_S (OFF)	Switch input capacitance "OFF" condition
C_D (OFF)	Switch output capacitance "OFF" condition
C_{IN}	Digital input capacitance
C_D, C_S (ON)	Input or output capacitance when the switch is on

t_{ON}	Delay time between the 50% and 90% points of the digital input and switch "ON" condition
t_{OFF}	Delay time between the 50% and 90% points of the digital input and switch "OFF" condition
t_{OPEN}	"OFF" time measured between 50% points of both switches, which are connected as a multiplexer, when switching from one address state to another
V_{INL}	Maximum Input Voltage for a Logic Low
V_{INH}	Minimum Input Voltage for a Logic High
I_{INL} (I_{INH})	Input current of the digital input
V_{DD}	Most positive voltage supply
V_{SS}	Most negative voltage supply
I_{DD}	Positive supply current
I_{SS}	Negative supply current

OUTLINE DIMENSIONS

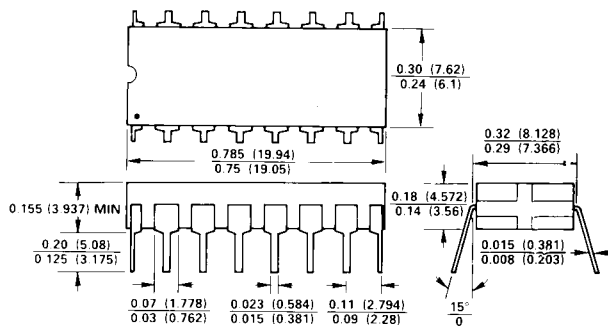
Dimensions shown in inches and (mm).

16-Pin Plastic (N-16)

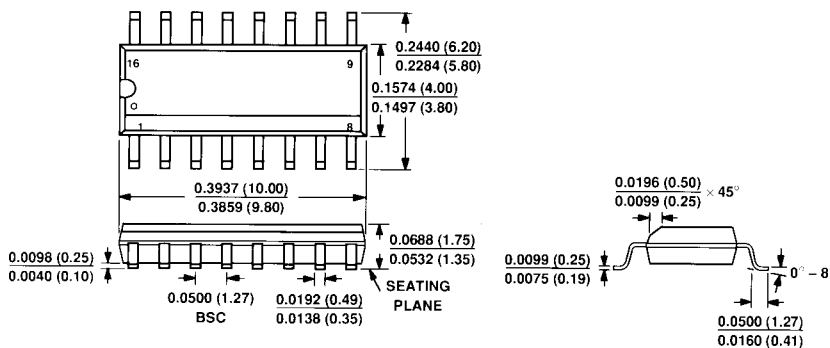


LEAD NO. 1 IDENTIFIED BY DOT OR NOTCH
LEADS ARE SOLDER OR TIN-PLATED KOVAR OR ALLOY 42

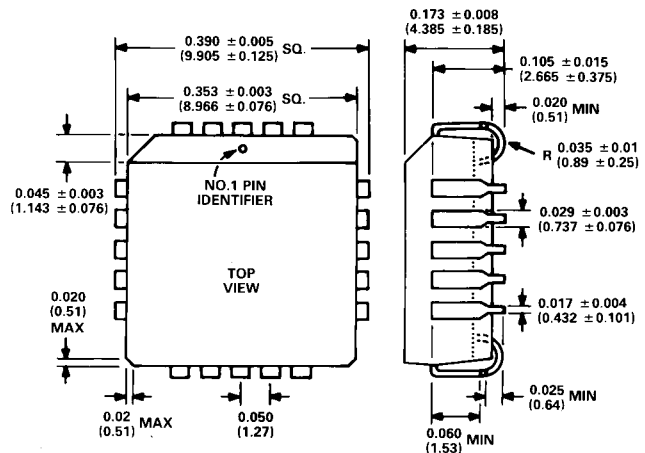
16-Pin Cerdip (Q-16)



16-Lead Narrow Body SOIC (R-16A)



20-Terminal Plastic Leaded Chip Carrier (P-20A)



20-Terminal Leadless Ceramic Chip Carrier (E-20A)

